



CD4519BM/CD4519BC 4-Bit AND/OR Selector

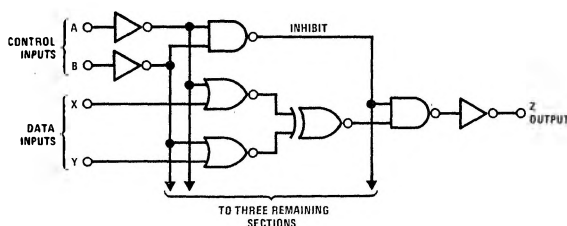
General Description

The CD4519B is a monolithic complementary MOS (CMOS) integrated circuit constructed with N- and P-channel enhancement mode transistors. Depending on the condition of the control inputs, this part provides three functions in one package: a 4-bit AND/OR selector, a quad 2-channel Data Selector, or a Quad Exclusive-NOR Gate. The device outputs have equal source and sink current capabilities and conform to the standard B series output drive and supply voltage ratings.

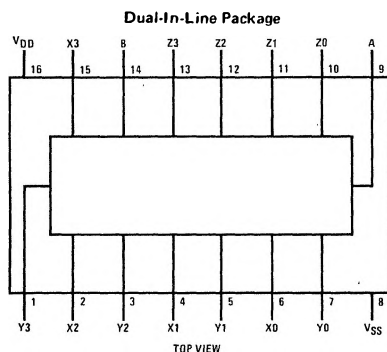
Features

- Wide supply voltage range 3.0V to 15V
- High noise immunity 0.45 V_{DD} (typ.)
- Low power TTL compatibility fan out of 2 driving 74L or 1 driving 74LS
- 5V-10V-15V parametric ratings
- Symmetrical output characteristics
- Maximum input leakage $1\mu A$ at 15V over full temperature range
- Second source of Motorola MC14519

Logic Diagram



Connection Diagram



Truth Table

CONTROL INPUTS		OUTPUT
A	B	Z_n
0	0	0
0	1	Y_n
1	0	X_n
1	1	$X_n \odot Y_n$

Note: $X_n \odot Y_n = \overline{X_n \odot Y_n} = X_n Y_n + \overline{X_n} \overline{Y_n}$

Absolute Maximum Ratings

(Notes 1 and 2)

V_{DD} dc Supply Voltage	-0.5 to +18 V _{DC}
V_{IN} Input Voltage	-0.5 to V_{DD} +0.5 V _{DC}
T_S Storage Temperature Range	-65°C to +150°C
P_D Package Dissipation	500 mW
T_L Lead Temperature (Soldering, 10 seconds)	300°C

Recommended Operating Conditions

(Note 2)

V_{DD} dc Supply Voltage	3 to 15 V _{DC}
V_{IN} Input Voltage	0 to V_{DD} V _{DC}
T_A Operating Temperature Range	-55°C to +125°C
CD4519BM	-40°C to +85°C
CD4519BC	

DC Electrical Characteristics CD4519BM (Note 2)

PARAMETER	CONDITIONS	-55°C		25°C			125°C		UNITS
		MIN	MAX	MIN	TYP	MAX	MIN	MAX	
I_{DD} Quiescent Device Current	$V_{DD} = 5V$		1		0.005	1		30	μA
	$V_{DD} = 10V$		2		0.006	2		60	μA
	$V_{DD} = 15V$		4		0.007	4		120	μA
V_{OL} Low Level Output Voltage	$ I_O < 1\mu A$								
	$V_{DD} = 5V$		0.05		0	0.05		0.05	V
	$V_{DD} = 10V$		0.05		0	0.05		0.05	V
V_{OH} High Level Output Voltage	$ I_O < 1\mu A$								
	$V_{DD} = 5V$	4.95		4.95	5		4.95		V
	$V_{DD} = 10V$	9.95		9.95	10		9.95		V
V_{IL} Low Level Input Voltage	$ I_O < 1\mu A$								
	$V_{DD} = 5V, V_O = 0.5V$ or 4.5V		1.5		2	1.5		1.5	V
	$V_{DD} = 10V, V_O = 1V$ or 9V		3.0		4	3.0		3.0	V
V_{IH} High Level Input Voltage	$ I_O < 1\mu A$								
	$V_{DD} = 5V, V_O = 0.5V$ or 4.5V	3.5		3.5	3		3.5		V
	$V_{DD} = 10V, V_O = 1V$ or 9V	7.0		7.0	6		7.0		V
I_{OL} Low Level Output Current	$V_{DD} = 5V, V_O = 0.4V$	0.64		0.51	0.88		0.36		mA
	$V_{DD} = 10V, V_O = 0.5V$	1.6		1.3	2.25		0.9		mA
	$V_{DD} = 15V, V_O = 1.5V$	4.2		3.4	8.8		2.4		mA
I_{OH} High Level Output Current	$V_{DD} = 5V, V_O = 4.6V$	-0.64		-0.51	-0.88		-0.36		mA
	$V_{DD} = 10V, V_O = 9.5V$	-1.6		-1.3	-2.25		-0.9		mA
	$V_{DD} = 15V, V_O = 13.5V$	-4.2		-3.4	-8.8		-2.4		mA
I_{IN} Input Current	$V_{DD} = 15V, V_{IN} = 0V$		-0.1		-10^{-5}	-0.1		-1.0	μA
	$V_{DD} = 15V, V_{IN} = 15V$		0.1		10^{-5}	0.1		1.0	μA

DC Electrical Characteristics CD4519BC (Note 2)

PARAMETER	CONDITIONS	-40°C		25°C			85°C		UNITS
		MIN	MAX	MIN	TYP	MAX	MIN	MAX	
I_{DD} Quiescent Device Current	$V_{DD} = 5V$		4			4		30	μA
	$V_{DD} = 10V$		8			8		60	μA
	$V_{DD} = 15V$		16			16		120	μA
V_{OL} Low Level Output Voltage	$ I_O < 1\mu A$								
	$V_{DD} = 5V$		0.05		0	0.05		0.05	V
	$V_{DD} = 10V$		0.05		0	0.05		0.05	V
V_{OH} High Level Output Voltage	$ I_O < 1\mu A$								
	$V_{DD} = 5V$	4.95		4.95	5		4.95		V
	$V_{DD} = 10V$	9.95		9.95	10		9.95		V
V_{IL} Low Level Input Voltage	$ I_O < 1\mu A$								
	$V_{DD} = 5V, V_O = 0.5V$ or 4.5V		1.5		2	1.5		1.5	V
	$V_{DD} = 10V, V_O = 1V$ or 9V		3.0		4	3.0		3.0	V
V_{IH} High Level Input Voltage	$ I_O < 1\mu A$								
	$V_{DD} = 5V, V_O = 0.5V$ or 4.5V	3.5		3.5	3		3.5		V
	$V_{DD} = 10V, V_O = 1V$ or 9V	7.0		7.0	6		7.0		V
I_{OL} Low Level Output Current	$V_{DD} = 5V, V_O = 0.4V$	0.64		0.51	0.88		0.36		mA
	$V_{DD} = 10V, V_O = 0.5V$	1.6		1.3	2.25		0.9		mA
	$V_{DD} = 15V, V_O = 1.5V$	4.2		3.4	8.8		2.4		mA
I_{OH} High Level Output Current	$V_{DD} = 5V, V_O = 4.6V$	-0.64		-0.51	-0.88		-0.36		mA
	$V_{DD} = 10V, V_O = 9.5V$	-1.6		-1.3	-2.25		-0.9		mA
	$V_{DD} = 15V, V_O = 13.5V$	-4.2		-3.4	-8.8		-2.4		mA
I_{IN} Input Current	$V_{DD} = 15V, V_{IN} = 0V$		-0.1		-10^{-5}	-0.1		-1.0	μA
	$V_{DD} = 15V, V_{IN} = 15V$		0.1		10^{-5}	0.1		1.0	μA

DC Electrical Characteristics (Cont'd.) CD4519BC (Note 2)

PARAMETER	CONDITIONS	-40°C		25°C			85°C		UNITS
		MIN	MAX	MIN	TYP	MAX	MIN	MAX	
V _{IL} Low Level Input Voltage	I _O < 1μA								
	V _{DD} = 5V, V _O = 0.5V or 4.5V		1.5		2	1.5		1.5	V
	V _{DD} = 10V, V _O = 1V or 9V		3.0		4	3.0		3.0	V
	V _{DD} = 15V, V _O = 1.5V or 13.5V		4.0		6	4.0		4.0	V
V _{IH} High Level Input Voltage	I _O < 1μA								
	V _{DD} = 5V, V _O = 0.5V or 4.5V	3.5		3.5	3		3.5		V
	V _{DD} = 10V, V _O = 1V or 9V	7.0		7.0	6		7.0		V
	V _{DD} = 15V, V _O = 1.5V or 13.5V	11.0		11.0	9		11.0		V
I _{OL} Low Level Output Current	V _{DD} = 5V, V _O = 0.4V	0.52		0.44	0.88		0.36		mA
	V _{DD} = 10V, V _O = 0.5V	1.3		1.1	2.25		0.9		mA
	V _{DD} = 15V, V _O = 1.5V	3.6		3.0	8.8		2.4		mA
I _{OH} High Level Output Current	V _{DD} = 5V, V _O = 4.6V	-0.52		-0.44	-0.88		-0.36		mA
	V _{DD} = 10V, V _O = 9.5V	-1.3		-1.1	-2.25		-0.9		mA
	V _{DD} = 15V, V _O = 13.5V	-3.6		-3.0	-8.8		-2.4		mA
I _{IN} Input Current	V _{DD} = 15V, V _{IN} = 0V		-0.3		-10 ⁻⁵	-0.3		-1.0	μA
	V _{DD} = 15V, V _{IN} = 15V		0.3		10 ⁻⁵	0.3		1.0	μA

AC Electrical Characteristics T_A = 25°C, C_L = 50 pF, R_L = 200 kΩ, t_r = t_f = 20 ns, unless otherwise specified.

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
t _{PHL} , t _{PLH} Propagation Delay High-to-Low Level or Low-to-High Level	(Figure 1) V _{DD} = 5V		180	360	ns
	V _{DD} = 10V		75	150	ns
	V _{DD} = 15V		60	120	ns
t _{THL} , t _{TLH} Transition Time	(Figure 1) V _{DD} = 5V		90	200	ns
	V _{DD} = 10V		50	100	ns
	V _{DD} = 15V		40	80	ns
C _{IN} Average Input Capacitance	Any Input (Note 3)		5	7.5	pF
C _{pD} Power Dissipation Capacity	Any Gate (Note 4)		25		pF

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed; they are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.

Note 2: V_{SS} = 0V unless otherwise specified.

Note 3: Capacitance is guaranteed by periodic testing.

Note 4: C_{pD} determines the no load ac power consumption of any CMOS device. For complete explanation, see 54C/74C Family characteristics application note AN-90.

AC Test Circuit and Switching Time Waveforms

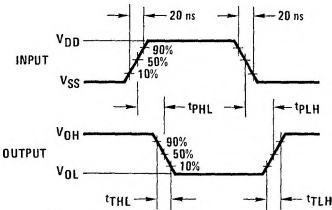
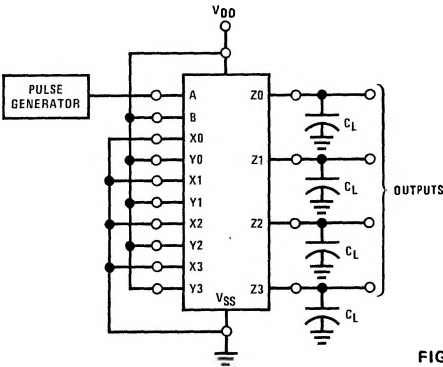
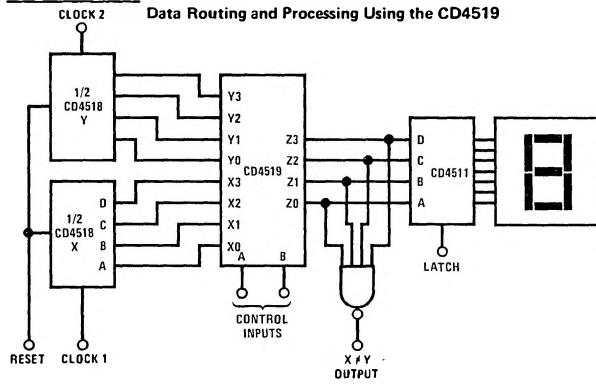


FIGURE 1

Typical Application

Data Routing and Processing Using the CD4519



CONTROL INPUTS		FUNCTION
A	B	
0	0	Display Zero
0	1	Display Counter Y
1	0	Display Counter X
1	1	Compare Counters